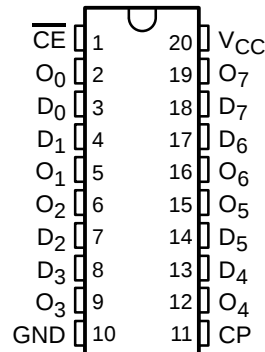
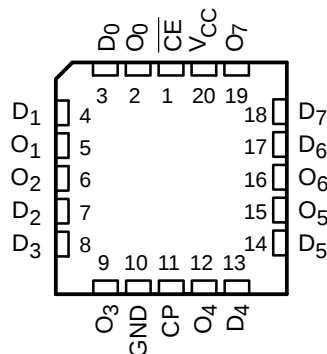


- Function, Pinout, and Drive Compatible With FCT and F Logic
- Reduced V_{OH} (Typically = 3.3 V) Versions of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I_{off} Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- Fully Compatible With TTL Input and Output Logic Levels
- Clock Enable for Address and Data Synchronization Application
- Eight Edge-Triggered D-Type Flip-Flops
- CY54FCT377T
 - 32-mA Output Sink Current
 - 12-mA Output Source Current
- CY74FCT377T
 - 64-mA Output Sink Current
 - 32-mA Output Source Current

SN74FCT377T . . . Q OR SO PACKAGE
(TOP VIEW)



SN54FCT377T . . . L PACKAGE
(TOP VIEW)



description

The 'FCT377T devices have eight triggered D-type flip-flops with individual data (D) inputs. The common buffered clock (CP) inputs load all flip-flops simultaneously when the clock-enable ($\overline{CE}$) input is low. The register is fully edge triggered. The state of each D input at one setup time before the low-to-high clock transition is transferred to the corresponding flip-flop output (O). $\overline{CE}$ must be stable only one setup time prior to the low-to-high clock transition for predictable operation.

These devices are fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

CY54FCT377T, CY74FCT377T
8-BIT REGISTERS

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ORDERING INFORMATION

T _A	PACKAGE†		SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	QSOP – Q	Tape and reel	5.2	CY74FCT377CTQCT	FCT377C
	SOIC – SO	Tube	5.2	CY74FCT377CTSOC	FCT377C
		Tape and reel	5.2	CY74FCT377CTSOCT	
	QSOP – Q	Tape and reel	7.2	CY74FCT377ATQCT	FCT377A
	SOIC – SO	Tube	7.2	CY74FCT377ATSOC	FCT377A
		Tape and reel	7.2	CY74FCT377ATSOCT	
–55°C to 125°C	QSOP – Q	Tape and reel	13	CY74FCT377TQCT	FCT377
	LCC – L	Tube	5.5	CY54FCT377CTLMB	
		Tube	8.3	CY54FCT377ATLMB	

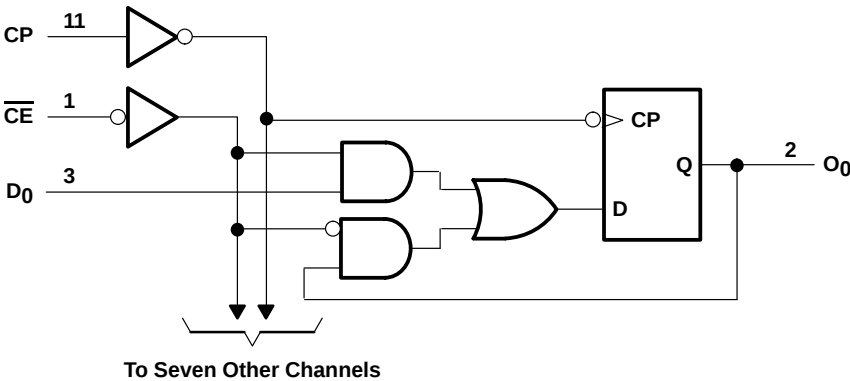
† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

INPUTS			OUTPUT O	OPERATING MODE
CP	$\overline{CE}$	D		
↑	L	h	H	Load 1
↑	L	L	L	Load 0
↑	h	X	No change	Hold
X	H	X		

H = High logic level, h = High logic level one setup time prior to the low-to-high clock transition, L = Low logic level, l = Low logic level one setup time prior to the low-to-high clock transition, X = Don't care, ↑ = Low-to-high clock transition

logic diagram



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range to ground potential	–0.5 V to 7 V
DC input voltage range	–0.5 V to 7 V
DC output voltage range	–0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, θ_{JA} (see Note 1): Q package	68°C/W
SO package	58°C/W
Ambient temperature range with power applied, T_A	–65°C to 135°C
Storage temperature range, T_{stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 2)

	CY54FCT377T			CY74FCT377T			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V_{IH} High-level input voltage	2			2			V
V_{IL} Low-level input voltage			0.8			0.8	V
I_{OH} High-level output current			–12			–32	mA
I_{OL} Low-level output current			32			64	mA
T_A Operating free-air temperature	–55		125	–40		85	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

CY54FCT377T, CY74FCT377T

8-BIT REGISTERS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	CY54FCT377T			CY74FCT377T			UNIT
		MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	
V_{IK}	$V_{CC} = 4.5\text{ V}$, $I_{IN} = -18\text{ mA}$		-0.7	-1.2				V
	$V_{CC} = 4.75\text{ V}$, $I_{IN} = -18\text{ mA}$					-0.7	-1.2	
V_{OH}	$V_{CC} = 4.5\text{ V}$, $I_{OH} = -12\text{ mA}$	2.4	3.3					V
	$V_{CC} = 4.75\text{ V}$				2			
					2.4	3.3		
V_{OL}	$V_{CC} = 4.5\text{ V}$, $I_{OL} = 32\text{ mA}$		0.3	0.55				V
	$V_{CC} = 4.75\text{ V}$, $I_{OL} = 64\text{ mA}$					0.3	0.55	
V_{hys}	All inputs		0.2			0.2		V
I_I	$V_{CC} = 5.5\text{ V}$, $V_{IN} = V_{CC}$			5				μA
	$V_{CC} = 5.25\text{ V}$, $V_{IN} = V_{CC}$						5	
I_{IH}	$V_{CC} = 5.5\text{ V}$, $V_{IN} = 2.7\text{ V}$			± 1				μA
	$V_{CC} = 5.25\text{ V}$, $V_{IN} = 2.7\text{ V}$						± 1	
I_{IL}	$V_{CC} = 5.5\text{ V}$, $V_{IN} = 0.5\text{ V}$			± 1				μA
	$V_{CC} = 5.25\text{ V}$, $V_{IN} = 0.5\text{ V}$						± 1	
$I_{OS}^{\ddagger}$	$V_{CC} = 5.5\text{ V}$, $V_{OUT} = 0\text{ V}$	-60	-120	-225				mA
	$V_{CC} = 5.25\text{ V}$, $V_{OUT} = 0\text{ V}$				-60	-120	-225	
I_{off}	$V_{CC} = 0\text{ V}$, $V_{OUT} = 4.5\text{ V}$			± 1			± 1	μA
I_{CC}	$V_{CC} = 5.5\text{ V}$, $V_{IN} \leq 0.2\text{ V}$, $V_{IN} \geq V_{CC} - 0.2\text{ V}$		0.1	0.2				mA
	$V_{CC} = 5.25\text{ V}$, $V_{IN} \leq 0.2\text{ V}$, $V_{IN} \geq V_{CC} - 0.2\text{ V}$					0.1	0.2	
ΔI_{CC}	$V_{CC} = 5.5\text{ V}$, $V_{IN} = 3.4\text{ V}^{\S}$, $f_1 = 0$, Outputs open		0.5	2				mA
	$V_{CC} = 5.25\text{ V}$, $V_{IN} = 3.4\text{ V}^{\S}$, $f_1 = 0$, Outputs open					0.5	2	

[†] Typical values are at $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$.

[‡] Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

[§] Per TTL-driven input ($V_{IN} = 3.4\text{ V}$); all other inputs at V_{CC} or GND

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS			CY54FCT377T			CY74FCT377T			UNIT
				MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	
I _{CCD} [¶]	V _{CC} = 5.5 V, Outputs open, One bit switching at 50% duty cycle, $\overline{CE}$ = GND, V _{IN} ≤ 0.2 V or V _{IN} ≥ V _{CC} – 0.2 V				0.06	0.12				mA/ MHz
	V _{CC} = 5.25 V, Outputs open, One bit switching at 50% duty cycle, $\overline{CE}$ = GND, V _{IN} ≤ 0.2 V or V _{IN} ≥ V _{CC} – 0.2 V							0.06	0.12	
I _C [#]	V _{CC} = 5.5 V, Outputs open, $\overline{f_0}$ = 10 MHz, $\overline{CE}$ = GND	One bit switching at f_1 = 5 MHz at 50% duty cycle	V _{IN} ≤ 0.2 V or V _{IN} ≥ V _{CC} – 0.2 V		0.7	1.4				mA
			V _{IN} = 3.4 V or GND		1.2	3.4				
		Eight bits switching at f_1 = 2.5 MHz at 50% duty cycle	V _{IN} ≤ 0.2 V or V _{IN} ≥ V _{CC} – 0.2 V		1.6	3.2				
			V _{IN} = 3.4 V or GND		3.9	12.2				
	V _{CC} = 5.25 V, Outputs open, $\overline{f_0}$ = 10 MHz, $\overline{CE}$ = GND	One bit switching at f_1 = 5 MHz at 50% duty cycle	V _{IN} ≤ 0.2 V or V _{IN} ≥ V _{CC} – 0.2 V					0.7	1.4	
			V _{IN} = 3.4 V or GND					1.2	3.4	
		Eight bits switching at f_1 = 2.5 MHz at 50% duty cycle	V _{IN} ≤ 0.2 V or V _{IN} ≥ V _{CC} – 0.2 V					1.6	3.2	
			V _{IN} = 3.4 V or GND					3.9	12.2	
C _i					5	10		5	10	pF
C ₀					9	12		9	12	pF

[†] Typical values are at $V_{CC} = 5$ V, $T_A = 25^\circ\text{C}$.

[¶] This parameter is derived for use in total power-supply calculations.

[#] $I_C = I_{CC} + \Delta I_{CC} \times D_H \times N_T + I_{CCD} (f_0/2 + f_1 \times N_1)$

Where:

I_C = Total supply current

I_{CC} = Power-supply current with CMOS input levels

ΔI_{CC} = Power-supply current for a TTL high input ($V_{IN} = 3.4$ V)

D_H = Duty cycle for TTL inputs high

N_T = Number of TTL inputs at D_H

I_{CCD} = Dynamic current caused by an input transition pair (HLH or LHL)

f_0 = Clock frequency for registered devices, otherwise zero

f_1 = Input signal frequency

N_1 = Number of inputs changing at f_1

All currents are in milliamperes and all frequencies are in megahertz.

|| Values for these conditions are examples of the I_{CC} formula.

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timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			CY54FCT377AT CY54FCT377CT		CY74FCT377T CY74FCT377AT CY74FCT377CT		UNIT
			MIN	MAX	MIN	MAX	
t _W	Pulse duration, CP high or low [†]		7		6		ns
t _{SU}	Setup time, high or low		Data before CP [↑]		2		ns
			$\overline{CE}$ before CP [↑]		3.5		
t _H	Hold time, high or low		Data after CP [↑]		1.5		ns
			$\overline{CE}$ after CP [↑]		1.5		

[†] With one data channel switching, $t_{W(L)} = t_{W(H)} = 4$ ns and $t_r = t_f = 1$ ns.

switching characteristics over operating free-air temperature range (see Figure 1)

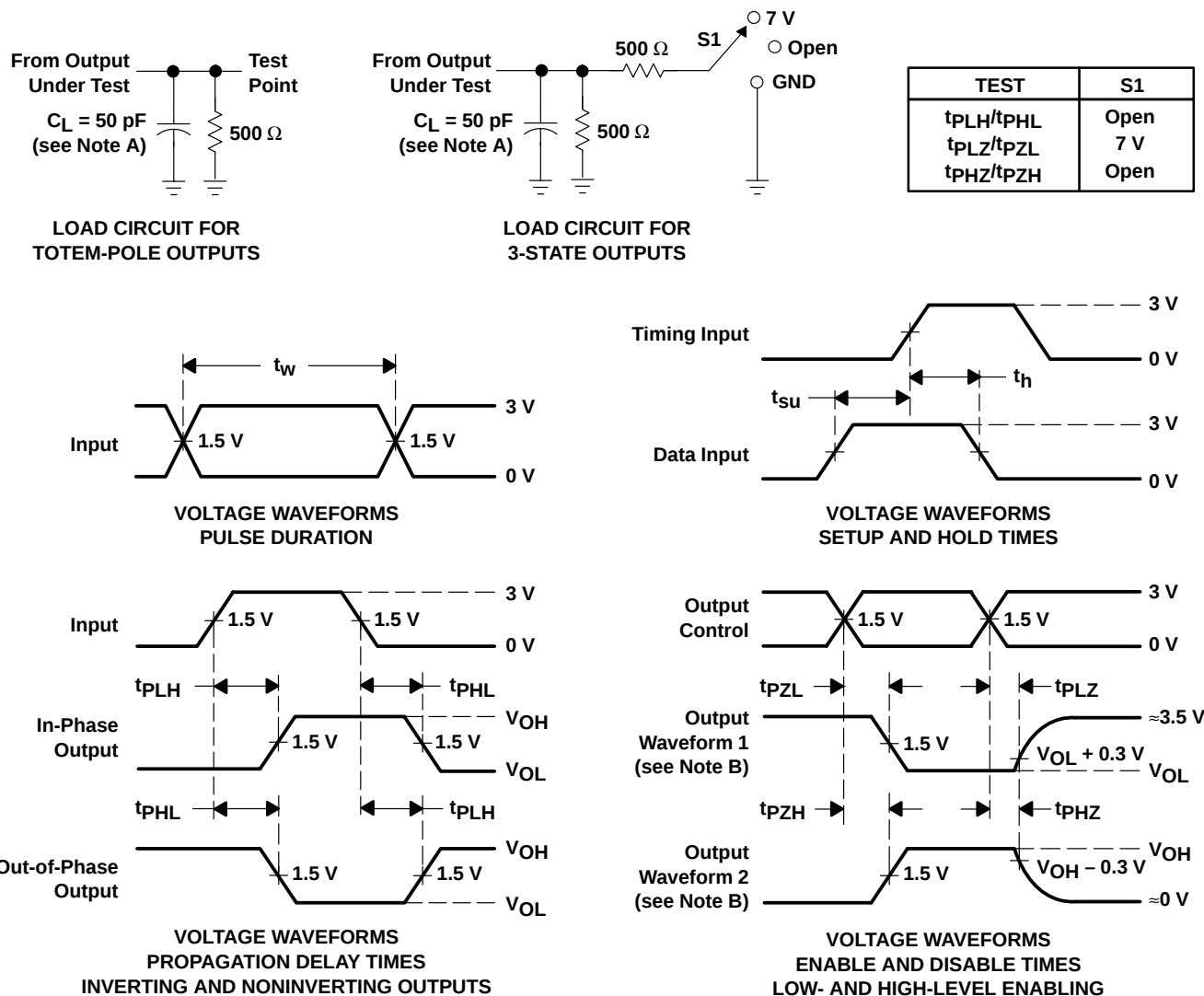
PARAMETER	FROM (INPUT)	TO (OUTPUT)	CY54FCT377AT		CY54FCT377CT		UNIT
			MIN	MAX	MIN	MAX	
t_{PLH}	CP	O	2	8.3	2	5.5	ns
t_{PHL}			2	8.3	2	5.5	

switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	CY74FCT377T		CY74FCT377AT		CY74FCT377CT		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	CP	O	2	13	2	7.2	2	5.2	ns
t_{PHL}			2	13	2	7.2	2	5.2	



PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
 B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-9221902M2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9221902M2A
5962-9221903M2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9221903M2A CY54FCT 377CTLMB
CY54FCT377CTLMB	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9221903M2A CY54FCT 377CTLMB
CY74FCT377ATQCT	Active	Production	SSOP (DBQ) 20	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT377A
CY74FCT377ATQCT.B	Active	Production	SSOP (DBQ) 20	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT377A
CY74FCT377ATQCTG4	Active	Production	SSOP (DBQ) 20	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT377A
CY74FCT377ATQCTG4.B	Active	Production	SSOP (DBQ) 20	2500 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT377A
CY74FCT377ATSOC	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT377A
CY74FCT377ATSOC.B	Active	Production	SOIC (DW) 20	25 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT377A

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

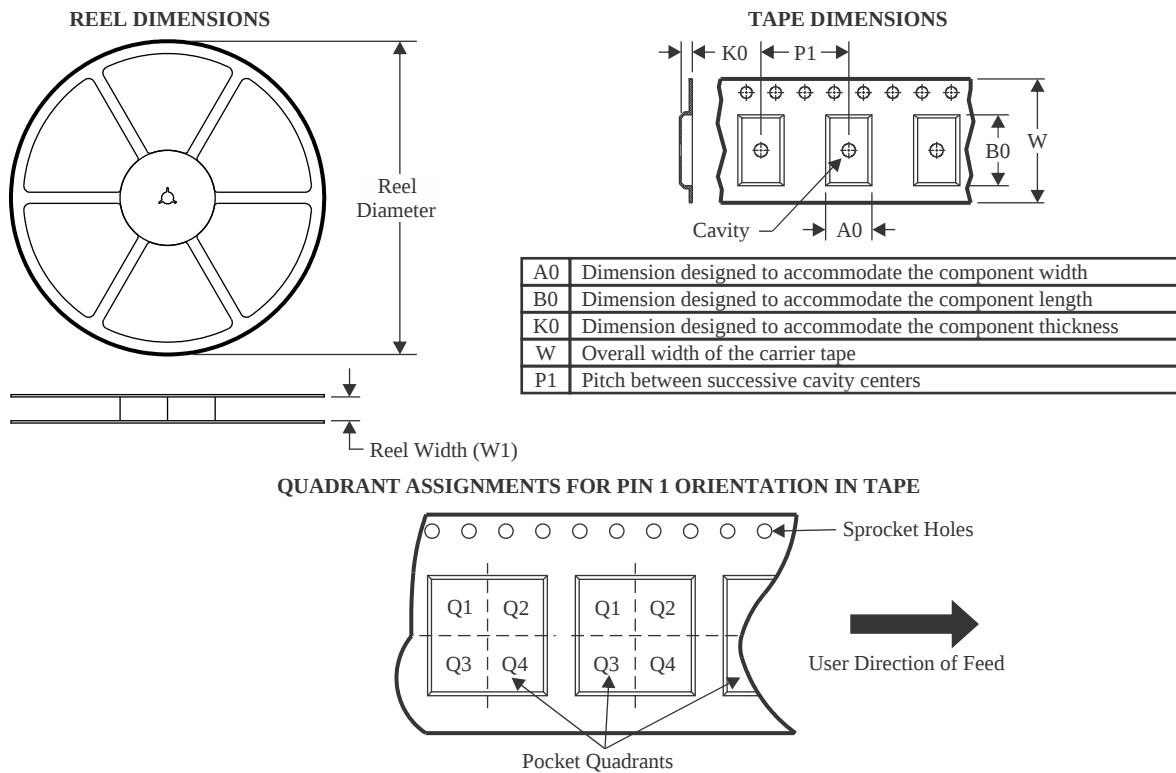
(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

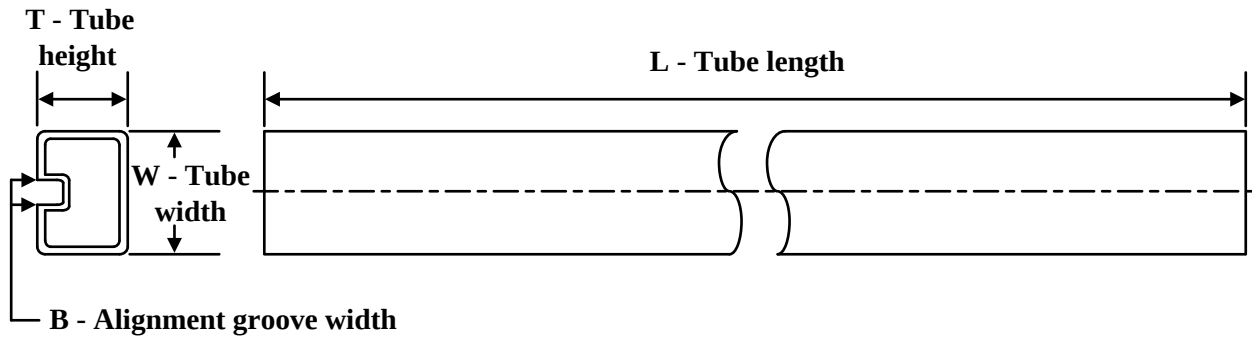
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT377ATQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT377ATQCTG4	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT377ATQCT	SSOP	DBQ	20	2500	353.0	353.0	32.0
CY74FCT377ATQCTG4	SSOP	DBQ	20	2500	353.0	353.0	32.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
5962-9221902M2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9221903M2A	FK	LCCC	20	55	506.98	12.06	2030	NA
CY54FCT377CTLMB	FK	LCCC	20	55	506.98	12.06	2030	NA
CY74FCT377ATSOC	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT377ATSOC.B	DW	SOIC	20	25	507	12.83	5080	6.6

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